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June 2014

## 74LVX08 **Low Voltage Quad 2-Input AND Gate**

#### **Features**

#### Input Voltage Level Translation from 5 V to 3 V

- Ideal for Low-power / Low-Noise 3.3 V Applications
- · Guaranteed Simultaneous Switching Noise Level and Dynamic threshold Performance

### **Description**

The LVX08 contains four 2-input AND gates. The inputs tolerate voltages up to 7 V allowing the interface of 5 V systems to 3 V systems.

## **Ordering Information**

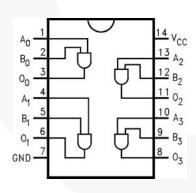
Part Number	Top Mark	Package	Packing Method	Packing Description
74LVX08M	LVX08	SOIC 14L	Rail	14-Lead Small Outline Integrated Circuit, JEDEC MS-012, 0.150 inch Narrow
74LVX08MX	LVX08	SOIC 14L	Tape and Reel	14-Lead Small Outline Integrated Circuit, JEDEC MS-012, 0.150 inch Narrow
74LVX08MTCX	LVX08	TSSOP 14L	Tape and Reel	14-Lead Thin Shrink Small Outline Package, JEDEC MO-153, 4.4 mm Wide

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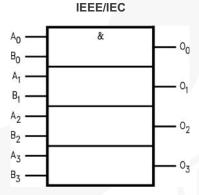


All packages are lead free per JEDEC: J-STD-020B standard.

## **Connection Diagram**



## **Logic Symbol**



## **Pin Description**

Pin Names	Description
A <sub>n</sub> , B <sub>n</sub>	Inputs
On	Outputs

## **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating			
V <sub>CC</sub>	Supply Voltage		-0.5 V to 7.0 V		
I <sub>IK</sub>	DC Input Diode Current, V <sub>I</sub> = -0.5 V		-20 mA		
V <sub>I</sub>	DC Input Voltage		-0.5 V to 7.0 V		
ı	DC Output Diode Current	V <sub>O</sub> = -0.5 V	-20 mA		
I <sub>OK</sub>	De Output Diode Current	$V_{O} = V_{CC} + 0.5 V$	+20 mA		
Vo	DC Output Voltage		-0.5 V to V <sub>CC</sub> + 0.5 V		
Io	DC Output Source or Sink Current		±25 mA		
I <sub>CC</sub> or I <sub>GND</sub>	DC V <sub>CC</sub> or Ground Current		±50 mA		
T <sub>STG</sub>	Storage Temperature		-65°C to 150°C		
Р	Power Dissipation		180 mW		
TL	Lead Temperature (Soldering, 10 seconds)		240°C		

## **Recommended Operating Conditions**(1)

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Rating
V <sub>CC</sub>	Supply Voltage	2.0 V to 3.6 V
V <sub>I</sub>	Input Voltage	0 V to 5.5 V
Vo	Output Voltage	0 V to V <sub>CC</sub>
$T_A$	Operating Temperature	-40°C to 85°C
Δt / ΔV	Input Rise and Fall Time	0 ns/V to 100 ns/V

#### Note:

1. Unused inputs must be held HIGH or LOW. They may not float.

## **DC Electrical Characteristics**

Symbol	Parameter	V <sub>CC</sub>	Conditions	T <sub>A</sub> = 25°C			T <sub>A</sub> = -40°C to +85°C		Unit
				Min.	Тур.	Max.	Min.	Max.	
		2.0		1.5			1.5		
$V_{IH}$	HIGH Level Input Voltage	3.0		2.0			2.0		V
	ronago	3.6		2.4			2.4		
		2.0				0.5		0.5	
$V_{IL}$	LOW Level Input Voltage	3.0				8.0		0.8	V
	ronago	3.6				8.0		0.8	
	HIGH Level Output Voltage	2.0	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OH} = -50 \mu A$	1.9	2.0		1.9		
V <sub>OH</sub>		3.0	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OH} = -50  \mu\text{A}$	2.9	3.0		2.9		V
			$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OH} = -4 \text{ mA}$	2.58			2.48		
	LOW Level Output Voltage	2.0	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OL} = -50 \mu\text{A}$		0.0	0.1		0.1	
$V_{OL}$		3.0	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OL} = -50  \mu\text{A}$		0.0	0.1		0.1	V
			$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OL} = -4 \text{ mA}$			0.36		0.44	
I <sub>IN</sub>	Input Leakage Current	3.6	V <sub>IN</sub> = 5.5 V or GND			±0.1		±1.0	μΑ
I <sub>CC</sub>	Quiescent Supply Current	3.6	$V_{IN} = V_{CC}$ or GND			2.0		20.0	μΑ

## Noise Characteristics(2)

Symbol	Parameter	<b>V</b> (\/)	C <sub>I</sub> (pF)	T <sub>A</sub> = 25°C		Unit
Syllibol	Falametei	V <sub>CC</sub> (V)	<b>C</b> [ (pi )	Тур.	Limit	Oilit
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>	3.3	50	0.3	0.5	V
V <sub>OLV</sub>	Quiet Output Minimum Dynamic V <sub>OL</sub>	3.3	50	-0.3	-0.5	V
V <sub>IHD</sub>	Minimum HIGH Level Dynamic Input Voltage	3.3	50		2.0	V
V <sub>ILD</sub>	Maximum LOW Level Dynamic Input Voltage	3.3	50		0.8	V

#### Note:

2. Input  $t_r = t_f = 3 \text{ ns}$ 

### **AC Electrical Characteristics**

Symbol	Parameter	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	T <sub>A</sub> = 25°C			T <sub>A</sub> = -4 +85	Unit	
				Min.	Тур.	Max.	Min.	Max.	
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay Time	2.7	15		6.3	11.4	1.0	13.5	ns
			50		8.8	14.9	1.0	17.0	
		3.3 ± 0.3	15		4.8	7.1	1.0	8.5	
			50		7.3	10.6	1.0	12.0	
t <sub>OSLH</sub> ,	. I CHITCHIT TO CHITCHIT SKEW(S)	2.7	50			1.5		1.5	ns
t <sub>OSHL</sub>		3.3	50			1.5		1.5	

#### Note:

3. Parameter guaranteed by design  $t_{OSLH} = I t_{PLHm} - t_{PLHn} I$ ,  $t_{OSHL} = I t_{PHLm} - t_{PHLn} I$ .

## Capacitance

Symbol	Parameter		T <sub>A</sub> = 25°C			T <sub>A</sub> = -40°C to +85°C	
		Min.	Тур.	Max.	Min.	Max.	\
C <sub>IN</sub>	Input Capacitance		4	10		10	pF
C <sub>PD</sub>	Power Dissipation Capacitance <sup>(4)</sup>		18				pF

#### Note:

4. C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:  $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} \times I_{CC}}{4 \text{ (per Gate)}}$ 





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